

Form PTO-1449 (MODIFIED)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO. 040301/0578		SERIAL NO. Unassigned	
INFORMATION DISCLOSURE CITATION <i>(Use several sheets if necessary)</i>		APPLICANT		Nobutoshi AOKI et al.			
		FILING DATE		GROUP ART UNIT			
		November 16, 1999		Unassigned			
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE IF APPROPRIATE
<i>J</i>	A1	5,356,821	10/1994	Naruse et al.	437	34	<i>JCS42 U.S. PTO 09/440928 11/16/99</i>
FOREIGN PATENT DOCUMENTS							
	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
							YES
<i>J</i>	A2	2876866	01/1999	Japan			Abstract
<i>J</i>	A3	4-25176	01/1992	Japan			Abstract
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)							
<i>J</i>	A4	Tsu-Jae King et al., <i>IEEE ELECTRON DEVICE LETTERS</i> vol 12, no. 10, "A Variable-Work-Function Polycrystalline-Si _{1-x} Ge _x Gate Material for Submicrometer CMOS Technologies, pp. 533-535, (10/10/91)					
EXAMINER <i>J</i>		DATE CONSIDERED <i>9/21/2001</i>					
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